

HD74ALVC166245A

16-Bit Dual-supply Bus Transceiver with 3-state Outputs

REJ03D0158-0200Z Rev.2.00 Jan.07.2004

Description

The HD74ALVC166245A has 16 bus transceivers with three state outputs in a 48-pin package. When (DIR) is high, data flows from the A inputs to the B outputs, and when (DIR) is low, data flows from the B inputs to the A outputs. A and B bus are separated by making enable input (\overline{OE}) high level. This 16-bit non-inverting bus transceiver uses two separate power-supply rails.

And this product has two terminals (V_{CCA} , V_{CCB}), V_{CCA} is connected with A bus side, V_{CCB} is connected with control input and B bus. V_{CCA} and V_{CCB} are isolated.

The A port is designed to track V_{CCA} , which accepts voltages from 1.2 V to 2.7 V, and the B port is designed to track V_{CCB} , which operates at 1.4 V to 3.6 V. Therefore, Bidirectional broad voltage conversion is possible.

Low voltage and high-speed operation is suitable at the battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

Features

- This product function as level shift transceiver that change V_{CCA} input level to V_{CCB} output level, V_{CCB} input level to V_{CCA} output level by providing different supply voltage to V_{CCA} and V_{CCB}.
- $V_{CCA} = 1.2 \text{ V}$ to 2.7 V, $V_{CCB} = 1.4 \text{ V}$ to 3.6 V ($V_{CCA} < V_{CCB}$)
- All control input V_I (max) = 3.6 V (@ V_{CCB} = 0 V to 3.6 V)
- All A bus side input outputs V_{I/O} (max) = 3.6 V (@V_{CCA} = 0 V or output off state)
- All B bus side input outputs V_{I/O} (max) = 3.6 V (@V_{CCB} = 0 V or output off state)
- High output current

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A bus side: \pm 2 mA (@V<sub>CCA</sub> = 1.2 V) B bus side: \pm 4 mA (@V<sub>CCB</sub> = 1.5\pm 0.1 V) \pm 6 mA (@V<sub>CCA</sub> = 1.5\pm 0.1 V) \pm 6 mA (@V<sub>CCB</sub> = 1.8\pm 0.15 V) \pm 18 mA (@V<sub>CCB</sub> = 2.5\pm 0.2 V) \pm 18 mA (@V<sub>CCB</sub> = 3.3\pm 0.3 V)
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• Ordering Information

			Package	Taping
Part Name	Package Type	Package Code	Abbreviation	Abbreviation (Quantity)
HD74ALVC166245ATEL	TSSOP-48Pin	TTP-48DBV	Т	EL (1,000pcs / Reel)

Function Table

Inputs

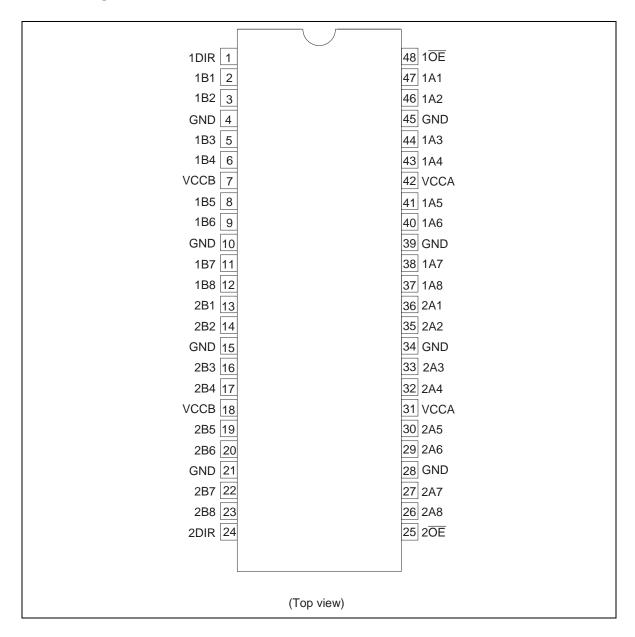
10E	1DIR	Operation
L	L	1B1-1B8 data to 1A1-1A8 bus
L	Н	1A1-1A8 data to 1B1-1B8 bus
Н	X	Z

Inputs

20E	2DIR	Operation
L	L	2B1–2B8 data to 2A1–2A8 bus
L	Н	2A1–2A8 data to 2B1–2B8 bus
Н	X	Z

H: High level
L: Low level
X: Immaterial
Z: High impedance

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V _{CCA} , V _{CCB}	-0.5 to 4.6	V	
Input voltage*1	VI	-0.5 to 4.6	V	DIR, OE
Input / output voltage	V _{I/O}	-0.5 to V _{CCA} +0.5	V	A port output "H" or "L"
		-0.5 to 4.6		A port output "Z" or V _{CCA} : OFF
		-0.5 to V _{CCB} +0.5	_	B port output "H" or "L"
		-0.5 to 4.6		B port output "Z" or V _{CCB} : OFF
Input diode current	I _{IK}	- 50	mA	V _I < 0
Output diode current	lok	-50	mA	V _O < 0
		50		V _O > V _{CC} +0.5
Output current	Io	±50	mA	
V _{CCA} , V _{CCB} , GND current	I _{CCA} , I _{CCB} , I _{GND}	100	mA	
Maximum power dissipation at Ta = 55°C (in still air)*2	P _T	850	mW	TSSOP
Storage temperature	Tstg	-65 to 150	°C	

Notes:

The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

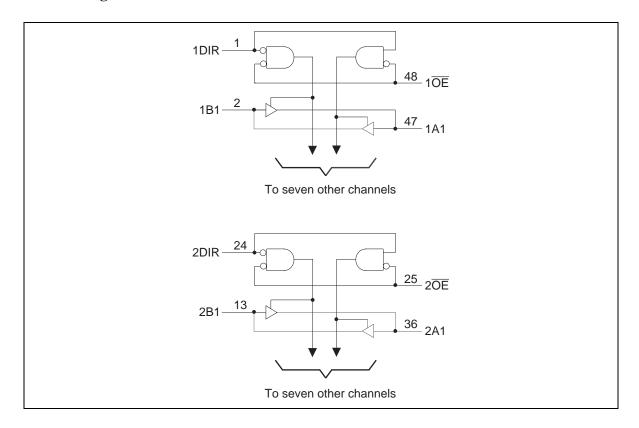
- 1. The input and output voltage ratings may be exceeded even if the input and output clamp-current ratings are observed.
- 2. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V _{CCB}	1.4 to 3.6	V	
	V _{CCA}	1.2 to 2.7		
Input / output voltage	VI	0 to 3.6	V	DIR, ŌĒ
	V _{I/O}	0 to V _{CCA}		A port output "H" or "L"
		0 to 3.6		A port output "Z" or V _{CCA} : OFF
		0 to V _{CCB}		B port output "H" or "L"
		0 to 3.6		B port output "Z" or V _{CCB} : OFF
output current	I _{OHB}	-4	mA	V _{CCB} = 1.5±0.1 V
		-6		V _{CCB} = 1.8±0.15 V
		-18		V _{CCB} = 2.5±0.2 V
		-24		V _{CCB} = 3.3±0.3 V
	I _{OHA}	-2		V _{CCA} = 1.2 V
		-4		V _{CCA} = 1.5±0.1 V
		-6		V _{CCA} = 1.8±0.15 V
		-18		V _{CCA} = 2.5±0.2 V
	I _{OLB}	4		V _{CCB} = 1.5±0.1 V
		6		V _{CCB} = 1.8±0.15 V
		18		V _{CCB} = 2.5±0.2 V
		24		V _{CCB} = 3.3±0.3 V
	I _{OLA}	2		V _{CCA} = 1.2 V
		4		V _{CCA} = 1.5±0.1 V
		6		V _{CCA} = 1.8±0.15 V
		18		$V_{CCA} = 2.5 \pm 0.2 \text{ V}$
Input transition rise or fall time	Δt / Δν	10	ns / V	
Operating temperature	Та	-40 to 85	°C	

Note: Unused or floating inputs must be held high or low.

Block Diagram



Electrical Characteristics

 $(Ta = -40 \text{ to } 85^{\circ}C)$

Item	Symbol	V _{CCB} (V)	V _{CCA} (V)	Min	Max	Unit	Test Conditions
Input voltage	V_{IHB}	1.5±0.1	1.2	V _{CCB} ×0.70	_	V	B port
		1.8±0.15	1.2 to 1.6	V _{CCB} ×0.65	_	_	Control input
		2.5±0.2	1.2 to 1.95	1.6	_	-	
		3.3±0.3	1.2 to 2.7	2.0	_	-	
	V _{IHA}	1.4 to 3.6	1.2	V _{CCA} ×0.75	_	-	A port
		1.65 to 3.6	1.5±0.1	V _{CCA} ×0.70	_	-	
		2.3 to 3.6	1.8±0.15	V _{CCA} ×0.65	_	-	
		3.0 to 3.6	2.5±0.2	1.6	_	-	
	V _{ILB}	1.5±0.1	1.2	_	V _{CCB} ×0.30	_	B port
		1.8±0.15	1.2 to 1.6	_	V _{CCB} ×0.35	_	Control input
		2.5±0.2	1.2 to 1.95	_	0.7	_	
		3.3±0.3	1.2 to 2.7	_	0.8	_	
	V _{ILA}	1.4 to 3.6	1.2	_	V _{CCA} ×0.25	_	A port
		1.65 to 3.6	1.5±0.1	_	V _{CCA} ×0.30	_	
		2.3 to 3.6	1.8±0.15	_	V _{CCA} ×0.35	_	
		3.0 to 3.6	2.5±0.2	_	0.7	_	
Output voltage	V _{OHB}	1.5±0.1	1.2	V _{CCB} -0.2	_	V	$I_{OH} = -100 \mu A$
				1.1	_	_	$I_{OH} = -4 \text{ mA}$
		1.8±0.15	1.2 to 1.6	V _{CCB} -0.2	_	_	$I_{OH} = -100 \ \mu A$
				1.25	_		$I_{OH} = -6 \text{ mA}$
		2.5±0.2	1.2 to 1.95	V _{CCB} -0.2	_	_	$I_{OH} = -100 \mu A$
				1.70	_	_	I _{OH} = -18 mA
		3.3±0.3	1.2 to 2.7	V _{CCB} -0.2	_	_	$I_{OH} = -100 \mu A$
				2.20	_	_	$I_{OH} = -24 \text{ mA}$
	V _{OHA}	1.4 to 3.6	1.2	V _{CCA} -0.2	_	_	$I_{OH} = -100 \mu A$
				0.90	_	_	$I_{OH} = -2 \text{ mA}$
		1.65 to 3.6	1.5±0.1	V _{CCA} -0.2	_	_	$I_{OH} = -100 \mu A$
				1.10	_	-	$I_{OH} = -4 \text{ mA}$
		2.3 to 3.6	1.8±0.15	V _{CCA} -0.2		_	$I_{OH} = -100 \ \mu A$
				1.25	_	_	$I_{OH} = -6 \text{ mA}$
		3.0 to 3.6	2.5±0.2	V _{CCA} -0.2	_	_	$I_{OH} = -100 \ \mu A$
				1.70	_	_	I _{OH} = -18 mA

Electrical Characteristics (Cont)

 $(Ta = -40 \text{ to } 85^{\circ}C)$

Item	Symbol	V _{CCB} (V)	V _{CCA} (V)	Min	Max	Unit	Test Conditions
Output voltage	V _{OLB}	1.5±0.1	1.2	_	0.2	V	I _{OL} = 100 μA
				_	0.3		I _{OL} = 4 mA
		1.8±0.15	1.2 to 1.6	_	0.2		I _{OL} = 100 μA
				_	0.3		I _{OL} = 6 mA
		2.5±0.2	1.2 to 1.95	_	0.2		I _{OL} = 100 μA
				_	0.6		I _{OL} = 18 mA
		3.3±0.3	1.2 to 2.7	_	0.2		I _{OL} = 100 μA
					0.55		I _{OL} = 24 mA
	V _{OLA}	1.4 to 3.6	1.2	_	0.2		I _{OL} = 100 μA
				_	0.3		I _{OL} = 2 mA
	1.65 to 3.6	1.5±0.1	_	0.2		I _{OL} = 100 μA	
					0.3		I _{OL} = 4 mA
		2.3 to 3.6	1.8±0.15	_	0.2		I _{OL} = 100 μA
					0.3		I _{OL} = 6 mA
		3.0 to 3.6	2.5±0.2	_	0.2		I _{OL} = 100 μA
					0.6		I _{OL} = 18 mA
Input current	I _{IN}	3.6	2.7	_	±5.0	μА	V _I = GND or V _{CCB} Control input
Off state output current	l _{OZ}	3.6	2.7	_	±10	μА	$V_{IN} = V_{IH} \text{ or } V_{IL}$
Output leak current	I _{OFF}	0	0	_	10	μΑ	$V_{IN}, V_{OUT} = 0 \text{ to } 3.6 \text{ V}$
Quiescent supply current	I _{CCB}	3.6	2.7	_	20	μΑ	I_O (B port) = 0, $A_{IN} = V_{CCA}$ or GND
	I _{CCA}	3.6	2.7	_	20		I_O (A port) = 0, $B_{IN} = V_{CCB}$ or GND
	I _{CCB}	3.6	2.7	_	±20		$V_{CCB} \le (V_{IN}, V_{OUT}) \le 3.6 \text{ V}$
	Icca	3.6	2.7	_	±20		$V_{CCA} \le (V_{IN}, V_{OUT}) \le 3.6 \text{ V}$
Increase in I _{CC} per Input* ¹	ΔI_{CCB}	3.6	2.7	_	750	μА	B port or control input One input at V _{CCB} -0.6 V Other input at V _{CCB} or GND
	ΔI_{CCA}	3.6	2.7	_	750	μΑ	A port One input at V _{CCA} -0.6 V Other input at V _{CCA} or GND

Notes: For condition shown as Min or Max use the appropriate values under recommended operating conditions

^{1.} This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

Capacitance

 $(Ta = 25^{\circ}C)$

Item	Symbo	ol V _{CCA} (V)	V _{CCB} (V)	Min	Тур	Max	Unit	Test Conditions
Control Input capacitance	C _{IN}	2.5	3.3	_	4	_	pF	$V_{I} = V_{CCB}$ or GND
Input / output capacitance	C _{I/O}	2.5	3.3	_	9	_	pF	A port, $V_I = V_{CCA}$ or GND, B port, $V_I = V_{CCB}$ or GND

Switching Characteristics

 $(Ta = -40 \text{ to } 85^{\circ}C)$

• $V_{CCB} = 3.3 \pm 0.3 \text{ V}, V_{CCA} = 2.5 \pm 0.2 \text{ V}$

Item	Symbo	ol Min	Тур	Max	Unit	Test conditions	From(Input)	To(Output)
Propagation delay	t _{PLH}	0.8	_	4.4	ns	C _L = 30 pF	В	Α
time	t _{PHL}	0.8	_	4.4		$R_L = 500 \Omega$		
	t _{PLH}	0.6	_	4.0			A	В
	t _{PHL}	0.6	_	4.0	_			
Output enable time	t _{zH}	0.8	_	4.6	ns	C _L = 30 pF	ŌĒ	A
	t _{ZL}	0.8	_	4.6	_	$R_L = 500 \Omega$		
	t _{ZH}	0.6	_	4.0			ŌE	В
	t _{ZL}	0.6	_	4.0	_			
Output disable time	t _{HZ}	0.8	_	4.4	ns	C _L = 30 pF	ŌĒ	A
	t _{LZ}	0.8	_	4.4		$R_L = 500 \Omega$		
	t _{HZ}	0.6	_	4.8			ŌE	В
	t _{LZ}	0.6	_	4.8	_			

 $(Ta = -40 \text{ to } 85^{\circ}C)$

• $V_{CCB} = 3.3\pm0.3 \text{ V}, V_{CCA} = 1.8\pm0.15 \text{ V}$

Item	Symb	ol Min	Тур	Max	Unit	Test conditions	From(Input)	To(Output)
Propagation delay	t _{PLH}	1.5	_	6.2	ns	C _L = 30 pF	В	Α
time	t _{PHL}	1.5	_	6.2		$R_L = 500 \Omega$		
	t _{PLH}	0.6	_	5.1	_		A	В
	t _{PHL}	0.6	_	5.1				
Output enable time	t _{ZH}	1.5	_	8.2	ns	C _L = 30 pF	ŌĒ	A
	t _{ZL}	1.5	_	8.2	_	$R_L = 500 \Omega$		
	t _{ZH}	0.6	_	5.1			ŌĒ	В
	t _{ZL}	0.6	_	5.1				
Output disable time	t _{HZ}	8.0	_	4.5	ns	C _L = 30 pF	ŌĒ	A
	t_{LZ}	0.8	_	4.5	_	$R_L = 500 \Omega$		
	t _{HZ}	0.6	_	5.6			ŌĒ	В
	t _{LZ}	0.6		5.6	_			

• $V_{CCB} = 3.3\pm0.3 \text{ V}, V_{CCA} = 1.5\pm0.1 \text{ V}$

Item	Symb	ol Min	Тур	Max	Unit	Test conditions	From(Input)	To(Output)
Propagation delay	t _{PLH}	1.5	_	5.5	ns	C _L = 30 pF	В	Α
time	t _{PHL}	1.5	_	5.5		$R_L = 500 \Omega$		
	t _{PLH}	0.6	_	5.5			A	В
	t _{PHL}	0.6	_	5.5	_			
Output enable time	t _{ZH}	1.5	_	10.0	ns	C _L = 30 pF	ŌĒ	A
	t _{ZL}	1.5	_	10.0	_	$R_L = 500 \Omega$		
	t _{ZH}	0.6	_	6.0			ŌE	В
	t _{ZL}	0.6	_	6.0	_			
Output disable time	t _{HZ}	1.5	_	6.0	ns	C _L = 30 pF	ŌĒ	Α
	t _{LZ}	1.5	_	6.0		$R_L = 500 \Omega$		
	t _{HZ}	0.6	_	6.0			ŌE	В
	t _{LZ}	0.6	_	6.0	_			

 $(Ta = -40 \text{ to } 85^{\circ}C)$

• $V_{CCB} = 3.3 \pm 0.3 \text{ V}, V_{CCA} = 1.2 \text{ V}$

Item	Symb	ol Min	Тур	Max	Unit	Test conditions	From(Input)	To(Output)
Propagation delay	t _{PLH}	_	4.0	_	ns	C _L = 30 pF	В	A
time	t _{PHL}	_	4.0	_		$R_L = 500 \Omega$		
	t _{PLH}	_	3.5	_			A	В
	t _{PHL}	_	3.5	_	_			
Output enable time	t _{ZH}	_	5.0	_	ns	C _L = 30 pF	ŌĒ	A
	t _{ZL}	_	5.0	_	_	$R_L = 500 \Omega$		
	t _{ZH}	_	2.5	_			ŌE	В
	t _{ZL}	_	2.5	_	_			
Output disable time	t _{HZ}	_	3.0	_	ns	C _L = 30 pF	ŌĒ	A
	t _{LZ}	_	3.0	_		$R_L = 500 \Omega$		
	t _{HZ}	_	2.5	_	_		ŌĒ	В
	t _{LZ}	_	2.5	_	_			

• $V_{CCB} = 2.5\pm0.2 \text{ V}, V_{CCA} = 1.8\pm0.15 \text{ V}$

Item	Symb	ol Min	Тур	Max	Unit	Test conditions	From(Input)	To(Output)
Propagation delay	t _{PLH}	1.5	_	5.8	ns	C _L = 30 pF	В	Α
time	t _{PHL}	1.5	_	5.8	_	$R_L = 500 \Omega$		
	t _{PLH}	0.8	_	5.5			A	В
	t _{PHL}	0.8	_	5.5	_			
Output enable time	t _{ZH}	1.5	_	8.3	ns	C _L = 30 pF	ŌĒ	A
	t _{ZL}	1.5	_	8.3		$R_L = 500 \Omega$		
	t _{ZH}	0.8	_	5.3	_		ŌĒ	В
	t _{ZL}	0.8	_	5.3				
Output disable time	t _{HZ}	0.8	_	4.6	ns	C _L = 30 pF	ŌĒ	A
	t _{LZ}	0.8	_	4.6	_	$R_L = 500 \Omega$		
	t _{HZ}	0.8		5.2	_		ŌĒ	В
	t _{LZ}	8.0	_	5.2	_			

 $(Ta = -40 \text{ to } 85^{\circ}C)$

• $V_{CCB} = 2.5\pm0.2 \text{ V}, V_{CCA} = 1.5\pm0.1 \text{ V}$

Item	Symb	ol Min	Тур	Max	Unit	Test conditions	From(Input)	To(Output)
Propagation delay	t _{PLH}	1.5	_	6.0	ns	C _L = 30 pF	В	Α
time	t _{PHL}	1.5	_	6.0		$R_L = 500 \Omega$		
	t _{PLH}	0.8	_	6.0			A	В
	t _{PHL}	0.8	_	6.0	_			
Output enable time	t _{zH}	1.5	_	10.0	ns	C _L = 30 pF	ŌĒ	A
	t _{ZL}	1.5	_	10.0	_	$R_L = 500 \Omega$		
	t _{ZH}	1.5	_	7.0			ŌE	В
	t _{ZL}	1.5	_	7.0				
Output disable time	t _{HZ}	1.5	_	6.0	ns	C _L = 30 pF	ŌĒ	A
	t _{LZ}	1.5	_	6.0		$R_L = 500 \Omega$		
	t _{HZ}	1.5	_	6.0			ŌE	В
	t _{LZ}	1.5	_	6.0	_			

• $V_{CCB} = 2.5 \pm 0.2 \text{ V}, V_{CCA} = 1.2 \text{ V}$

Item	Symb	ol Min	Тур	Max	Unit	Test conditions	From(Input)	To(Output)
Propagation delay	t _{PLH}	_	4.0	_	ns	C _L = 30 pF	В	A
time	t _{PHL}	_	4.0	_		$R_L = 500 \Omega$		
	t _{PLH}	_	3.5	_			A	В
	t _{PHL}	_	3.5	_	_			
Output enable time	t _{ZH}	_	5.5	_	ns	C _L = 30 pF	ŌĒ	Α
	t _{ZL}	_	5.5	_		$R_L = 500 \Omega$		
	t _{ZH}	_	3.5	_	_		ŌĒ	В
	t _{ZL}	_	3.5	_				
Output disable time	t _{HZ}	_	3.0	_	ns	C _L = 30 pF	ŌĒ	Α
	t _{LZ}	_	3.0	_	_	$R_L = 500 \Omega$		
	t _{HZ}	_	2.5	_			ŌĒ	В
	t _{LZ}	_	2.5	_				

 $(Ta = -40 \text{ to } 85^{\circ}C)$

• $V_{CCB} = 1.8\pm0.15 \text{ V}, V_{CCA} = 1.5\pm0.1 \text{ V}$

Item	Symbo	ol Min	Тур	Max	Unit	Test conditions	From(Input)	To(Output)
Propagation delay	t _{PLH}	1.5	_	7.0	ns	C _L = 30 pF	В	Α
time	t _{PHL}	1.5	_	7.0	_	$R_L = 500 \Omega$		
	t _{PLH}	1.5	_	7.0			A	В
	t _{PHL}	1.5	_	7.0				
Output enable time	t _{ZH}	1.5	_	10.0	ns	C _L = 30 pF	ŌĒ	A
	t _{ZL}	1.5	_	10.0		$R_L = 500 \Omega$		
	t _{ZH}	1.5	_	8.0	_		ŌE	В
	t _{ZL}	1.5	_	8.0				
Output disable time	t _{HZ}	1.5	_	6.0	ns	C _L = 30 pF	ŌĒ	A
	t _{LZ}	1.5	_	6.0		$R_L = 500 \Omega$		
	t _{HZ}	1.5	_	7.0	_		ŌE	В
	t _{LZ}	1.5	_	7.0				

• $V_{CCB} = 1.8 \pm 0.15 \text{ V}, V_{CCA} = 1.2 \text{ V}$

Item	Symb	ol Min	Тур	Max	Unit	Test conditions	From(Input)	To(Output)
Propagation delay	t _{PLH}	_	4.5	_	ns	C _L = 30 pF	В	A
time	t _{PHL}	_	4.5	_		$R_L = 500 \Omega$		
	t _{PLH}		4.0	_	_		A	В
	t _{PHL}		4.0	_	_			
Output enable time	t _{ZH}		6.0	_	ns	C _L = 30 pF	ŌĒ	Α
	t _{ZL}	_	6.0	_		$R_L = 500 \Omega$		
	t _{ZH}	_	4.5	_			ŌĒ	В
	t _{ZL}		4.5	_	_			
Output disable time	t _{HZ}	_	3.5	_	ns	C _L = 30 pF	ŌĒ	Α
	t _{LZ}		3.5	_	_	$R_L = 500 \Omega$		
	t _{HZ}	_	3.5	_			ŌE	В
	t _{LZ}	_	3.5	_	_			

 $(Ta = -40 \text{ to } 85^{\circ}C)$

• $V_{CCB} = 1.5 \pm 0.1 \text{ V}, V_{CCA} = 1.2 \text{ V}$

Item	Symb	ol Min	Тур	Max	Unit	Test conditions	From(Input)	To(Output)
Propagation delay	t _{PLH}	_	5.0	_	ns	C _L = 30 pF	В	A
time	t _{PHL}		5.0	_		$R_L = 500 \Omega$		
	t _{PLH}	_	5.0	_			A	В
	t _{PHL}	_	5.0	_	_			
Output enable time	t _{ZH}		7.0	_	ns	C _L = 30 pF	ŌE	A
	t _{ZL}	_	7.0	_	_	$R_L = 500 \Omega$		
	t _{ZH}		6.0	_			ŌE	В
	t _{ZL}		6.0	_				
Output disable time	t _{HZ}	_	4.5	_	ns	C _L = 30 pF	ŌĒ	A
	t _{LZ}		4.5	_		$R_L = 500 \Omega$		
	t _{HZ}	_	4.0	_			ŌĒ	В
	t_{LZ}	_	4.0	_	_			

Operating Characteristics

Item	Symbo	ol V _{CCA} (V)	V _{CCB} (V)	Min	Тур	Max	Unit	Test Conditions
Power dissipation capacitance	C_{PD}	2.5	3.3	_	40	_	pF	$f = 10 \text{ MHz}$ $C_L = 0$

Power-up considerations

Level-translation devices offer an opportunity for successful mixed-voltage signal design.

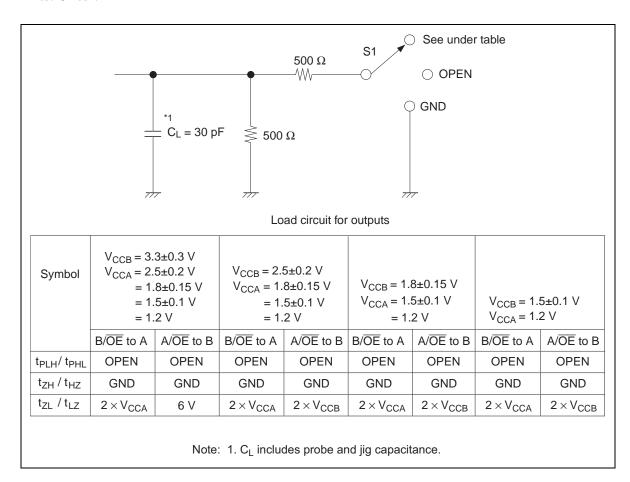
A proper power-up sequence always should be followed to avoid excessive supply current, bus contention, oscillations, or other anomalies caused by improperly biased device pins.

Take these precautions to guard against such power-up problems.

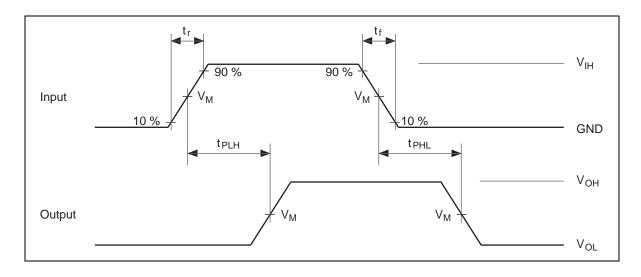
- 1. Connect ground before any supply voltage is applied.
- 2. Next, power up the control side of the device. (Power up of V_{CCB} is first. Next power up is V_{CCA} .)
- 3. Tie \overline{OE} to V_{CCB} with a pullup resistor so that it ramps with V_{CCB} .
- Depending on the direction of the data path, DIR can be high or low.
 If DIR high is needed (A data to B bus), ramp it with V_{CCB}. Otherwise, DIR low is needed (B data to A bus), ramp it with GND.



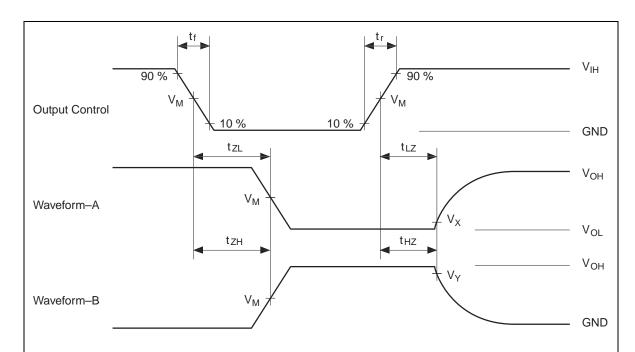
Test Circuit



Waveforms - 1



Waveforms-2

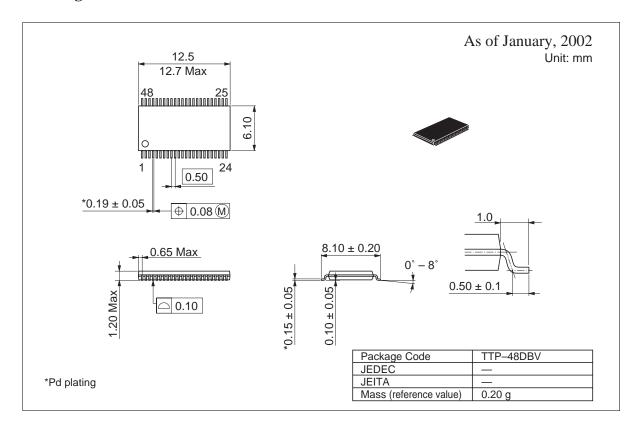


Cumbal			V_{CC}		
Symbol	3.3±0.3 V	2.5±0.2 V	1.8±0.15 V	1.5±0.1 V	1.2 V
V_{IH}	2.7 V	V _{CC}	V _{CC}	V _{CC}	V _{CC}
V_{M}	1.5 V	1/2 V _{CC}	1/2 V _{CC}	1/2 V _{CC}	1/2 V _{CC}
V _X	V _{OL} +0.3 V	V _{OL} +0.15 V	V _{OL} +0.15 V	V _{OL} +0.1 V	V _{OL} +0.1 V
V_{Y}	V _{OH} -0.3 V	V _{OH} -0.15 V	V _{OH} -0.15 V	V _{OH} -0.1 V	V _{OH} -0.1 V

Notes: 1. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Zo = 50 Ω , $t_f \leq$ 2.0 ns, $t_f \leq$ 2.0 ns.

- 2. Waveform A is for an output with internal conditions such that the output is low except when disabled by the output control.
- 3. Waveform B is for an output with internal conditions such that the output is high except when disabled by the output control.
- 4. The output are measured one at a time with one transition per measurement.

Package Dimensions



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Renesas Technology America, Inc.

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Renesas Technology Europe GmbHDornacher Str. 3, D-85622 Feldkirchen, Germany
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Renesas Technology Hong Kong Ltd. 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2375-6836

Renesas Technology Taiwan Co., Ltd. FL 10, #99, Fu-Hsing N. Rd., Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 2713-2999

Renesas Technology (Shanghai) Co., Ltd. 26/F., Ruijin Building, No.205 Maoming Road (S), Shanghai 200020, China Tel: <86> (21) 6472-1001, Fax: <86> (21) 6415-2952

Renesas Technology Singapore Pte. Ltd.
1, Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001